# **GLAST Conductive Glue Discussion**

Gwelen Paliaga SCIPP 3/9/00

### REQUIREMENTS

- ♦ Room temperature cure. (?)
- ♦ Compliant (to avoid stress concentration at bond edges)
- ♦ Thixotropic (doesn't flow)
- ♦ High Strength (to prevent ladder buckling and bond line peeling- recent results)
- ♦ Operating temperature -55 C to 60 C
- ♦ Meets NASA outgassing specs
- ♦ Safe for semiconductors (low ion content)

## <u>USE</u>

- Mechanical and electrical connection of SSD to Kapton bias circuit.
- 4 mil bond line (can be adjusted, but affects tower geometry).

## **ISSUES**

- ♦ Silver migration
- ♦ Aging
- ♦ Room temperature cure with low outgassing
- ♦ Ion content

### **CANIDATES**

Company	Name	NASA	Min. Cure	Comments
		approved	Temp, (C)	
Nusil	CV-2640	Yes	25	Silicone, carbon filled, resistivity
				icreased a lot with thermo-cycling
AI	ME8456	Yes	80	Compliant, benchmark material for
Technology				NASA, Lockhead, Boeing
Epo-Tek	H20E	Yes	50	
Epo-Tek	8 other possibilities	YES	High	